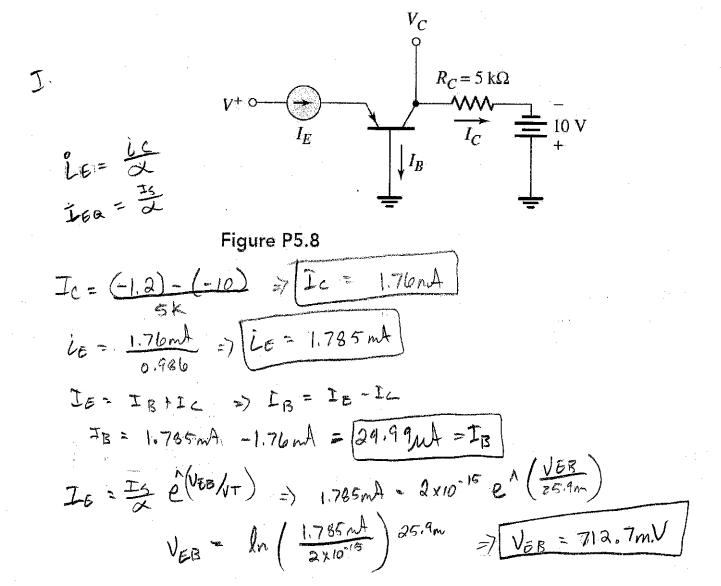
# Homework 5 Due Date Thursday, Feb 28th, in class

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HW 5, ECE 322L

(a) The pnp transistor shown in Figure P5.8 has a common-base current gain  $\alpha = 0.9860$ . Determine the emitter current such that  $V_C = -1.2$  V. What is the base current? (b) Using the results of part (a) and assuming  $I_{EQ} = 2 \times 10^{-15}$  A, determine  $V_{EB}$ .



For all the transistors in Figure P5.17,  $\beta = 75$ . The results of some measurements are indicated on the figures. Find the values of the other labeled currents, voltages, and/or resistor values.

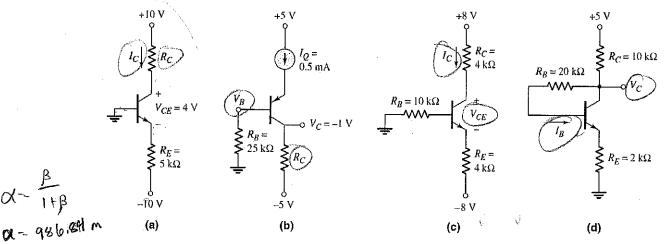


Figure P5.17

a) 
$$-V_{BE} - I_{ER} = (-10) = 0$$

$$\frac{\left(-V_{BE} + 10\right)}{R_{E}} = I_{E} = \frac{\left(-0.7 + 10\right)}{5 \text{ K}}$$

$$I_{E} = I_{1.8} \text{ b mA}$$

$$I_{E} = \frac{1}{2} \text{ c} \Rightarrow I_{C} = \alpha(I_{E})$$

$$I_{C} = 0.98684 (1.86 \text{ mA})$$

$$I_{C} = 1.836 \text{ mA}$$

$$V = I_{R} \Rightarrow R = \frac{1}{4}$$

$$R_{C} = \frac{10 - 4}{1.836 \text{ mA}} \Rightarrow \frac{R_{C} = 3.269 \text{ K}\Omega}{R_{C}}$$

$$P_{B} = \alpha L_{E} \Rightarrow \frac{1}{R_{E}} = \frac{\alpha L_{E}}{R_{E}}$$

$$\Rightarrow I_{B} = 6.579 \text{ aA}$$

$$V_{B} = I_{B} R_{B} \Rightarrow (6.57 \text{ mA})(254)$$

$$V_{B} = I_{B} + I_{B} \Rightarrow I_{C} = 0.5 \text{ mA} - 6.57 \text{ mA}$$

$$I_{C} = 493.92 \text{ mA}$$

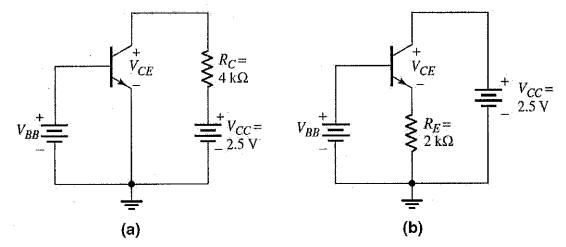
$$I_{C} = 493.92 \text{ mA}$$

$$I_{C} = 493.92 \text{ mA}$$

C) 
$$0 - I_E R_B + V_{BE} - I_E R_E - (4) = 0 \Rightarrow$$
 $7.3 = I_B R_P + I_C R_E = (1+\beta)I_B$ 
 $I_B = \frac{7.3}{10K + (1+\lambda)4K} \Rightarrow I_B = 23.25 \mu\text{A}$ 
 $V_B = I_B R_B \Rightarrow V_B = 23.5 \mu\text{A}$ 
 $V_B = I_B R_B \Rightarrow V_B = 23.5 \mu\text{A}$ 
 $V_{RE} = I_E R_E \Rightarrow (1.747 \mu\text{A})4K \Rightarrow 7.068 V$ 
 $I_C = BI_R \Rightarrow I_C = 7.5(23.25 \mu\text{A}) \Rightarrow I_C = 1.744 \mu\text{A}$ 
 $V_{RC} = I_C R_C \Rightarrow 1.744 \mu\text{A}(4K) \Rightarrow V_{RC} = 4.975 V$ 
 $V_{CE} = I.958 V$ 

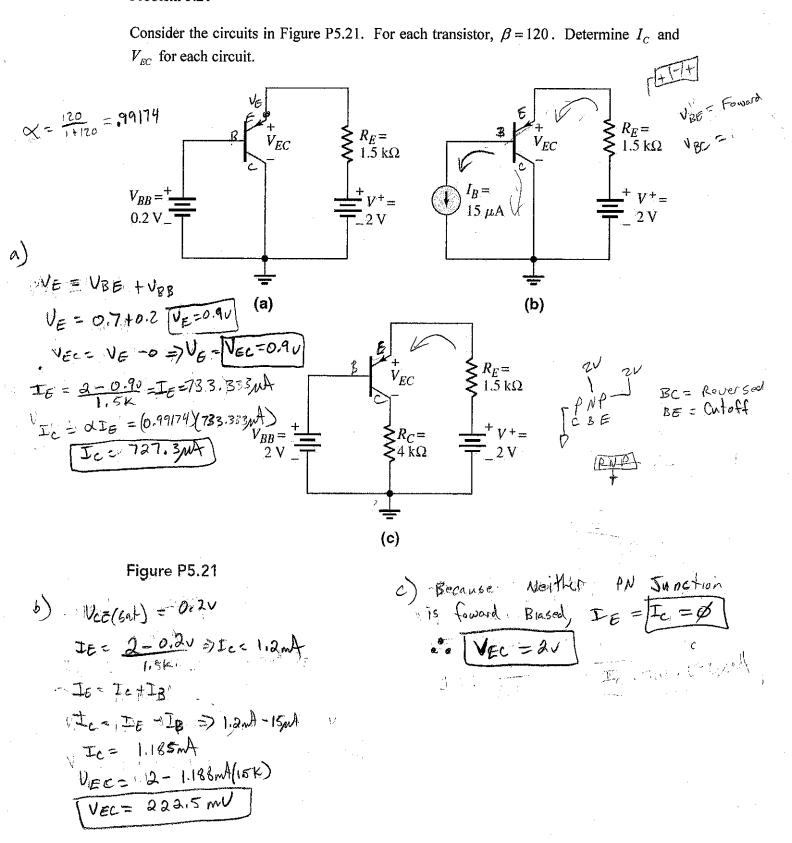
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Consider the two circuits in Figure P5.19. The parameters of each transistor are  $I_S = 5 \times 10^{-16}$  A and  $\beta = 90$ . Determine  $V_{BB}$  in each circuit such that  $V_{CE} = 1.10$  V.



VBB = VBE

a) 
$$I_{c} = \frac{V_{cc} - V_{ce}}{R_{c}} = \frac{7.5 - 1}{4R}$$
 $I_{c} = \frac{350 \mu A}{1}$ 
 $I_{c} = I_{s} e^{r} \left( \frac{V_{BE}}{V_{T}} \right)$ 
 $V_{BE} = 0.259 \left( l_{n} \left( \frac{350 \mu A}{5 \times 10^{-16}} \right) \right)$ 
 $V_{BE} = 0.706 V$ 



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In the circuits shown in Figure P5.23, the values of measured parameters are shown. Determine  $\beta$ ,  $\alpha$ , and the other labeled currents and voltages. Sketch the dc load line and plot the *O*-point.

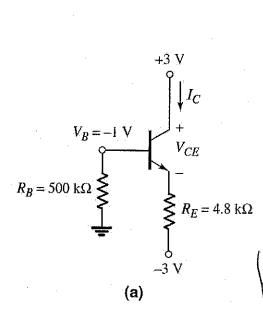


Figure P5.23

Figure P5.23

A) 
$$-1-0.7 - I_E R_E - (-3) = 0$$
 $I_E = \frac{3-1-0.7}{4.8E} = I_E = 270.833MA$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_B R_B + (I_E - I_B)R_C - 5 + 0$ 
 $V_E = I_E R_C + 5 + 0$ 
 $V_E = I_E R_C +$ 

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+5 V  $R_B = 100 \text{ k}\Omega$  $R_C = 8 k\Omega$ b) IE = 5-4 = 50 put = IE VE-VBE (ON)-IR RB - ICRC - (-50) =0 Ve = IBRB + (IE-IB) Rc - 5+0.7 VE = IB(RB-RC) + IERC - 5 +0.7 IB = VB - IERC+5 => (4-600ml/(9k)+5)-0.7 RB-RE 100K-8K Ic = IE - IB => 500M - 46.74 = Ic = 453, 26, WA B= = 453.26M = B= 9.698 W.79,M X= 1+B= = 0.9065=X

5.37v